# **Complementary Silicon Plastic Power Darlingtons**

... for use as output devices in complementary general purpose amplifier applications.

#### **Features**

- High DC Current Gain HFE = 1000 (min) @ 5 Adc
- Monolithic Construction with Built-in Base Emitter Shunt Resistors
- These are Pb-Free Devices\*

#### **MAXIMUM RATINGS**

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	$V_{CEO}$	100	Vdc
Collector-Base Voltage	V <sub>CB</sub>	100	Vdc
Emitter-Base Voltage	$V_{EB}$	5.0	Vdc
Collector Current - Continuous - Peak	I <sub>C</sub>	10 20	Adc
Base Current	Ι <sub>Β</sub>	0.5	Adc
Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	125 1.0	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.0	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

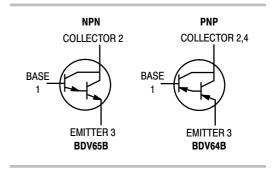
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

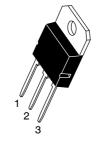


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# 10 AMPERE DARLINGTON COMPLEMENTARY SILICON POWER TRANSISTORS 60-80-100-120 VOLTS, 125 WATTS





SOT-93 (TO-218) CASE 340D



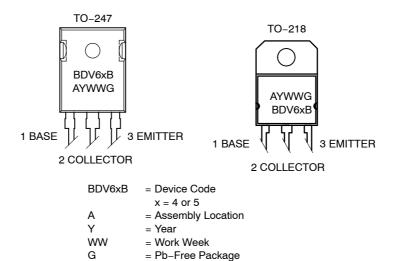
TO-247 CASE 340L STYLE 3

NOTE: Effective June 2012 this device will be available only in the TO-247 package. Reference FPCN# 16827.

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **MARKING DIAGRAMS**



#### **ORDERING INFORMATION**

Device Order Number	Package Type	Shipping
BDV65BG	TO-218 (Pb-Free)	30 Units / Rail
BDV64BG	TO-218 (Pb-Free)	30 Units / Rail
BDV65BG	TO-247 (Pb-Free)	30 Units / Rail
BDV64BG	TO-247 (Pb-Free)	30 Units / Rail

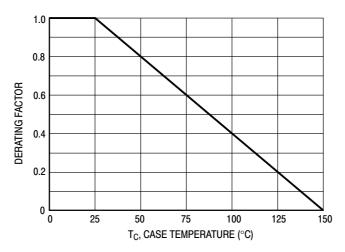
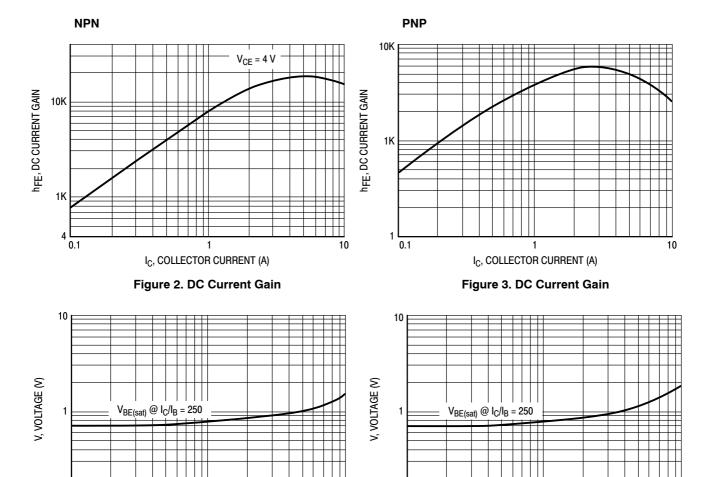


Figure 1. Power Derating

#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	<b>-</b>	l .		1
Collector–Emitter Sustaining Voltage (1) $(I_C = 30 \text{ mAdc}, I_B = 0)$	V <sub>CEO(sus)</sub>	100	_	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 50 Vdc, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	1.0	mAdc
Collector Cutoff Current (V <sub>CB</sub> = 100 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	0.4	mAdc
Collector Cutoff Current $(V_{CB} = 50 \text{ Vdc}, I_E = 0, T_C = 150^{\circ}\text{C})$	I <sub>CBO</sub>	-	2.0	mAdc
Emitter Cutoff Current (V <sub>BE</sub> = 5.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	-	5.0	mAdc
ON CHARACTERISTICS	<u>.</u>			
DC Current Gain (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 4.0 Vdc)	h <sub>FE</sub>	1000	-	-
Collector–Emitter Saturation Voltage ( $I_C = 5.0$ Adc, $I_B = 0.02$ Adc)	V <sub>CE(sat)</sub>	-	2.0	Vdc
Base-Emitter Saturation Voltage (I <sub>C</sub> = 5.0 Adc, V <sub>CE</sub> = 4.0 Vdc)	V <sub>BE(on)</sub>	-	2.5	Vdc



0.1 - 0.1

10

I<sub>C</sub>, COLLECTOR CURRENT (A)

Figure 4. "On" Voltages

0.1 -

I<sub>C</sub>, COLLECTOR CURRENT (A)

Figure 5. "On" Voltages

10

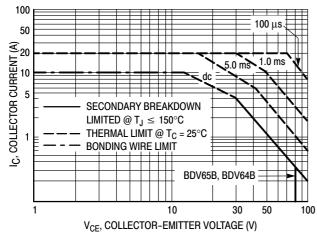


Figure 6. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C$  –  $V_{CE}$  limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on  $T_{J(pk)} = 150$ °C,  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150$ °C.  $T_{J(pk)}$  may be calculated from the data in Figure 7. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

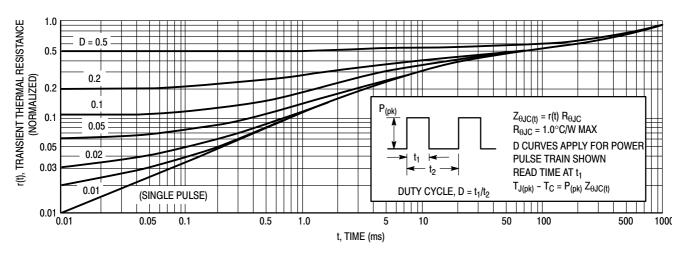
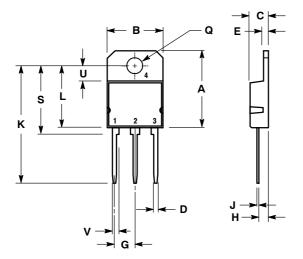


Figure 7. Thermal Response

#### PACKAGE DIMENSIONS

#### SOT-93 (TO-218) CASE 340D-02 **ISSUE E**



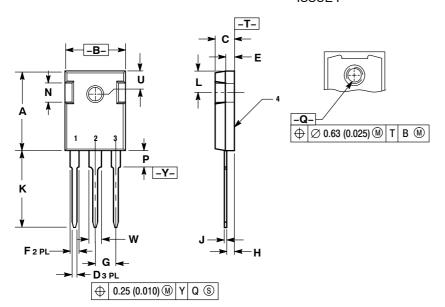
- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		IMETERS INCHES	
DIM	MIN	MAX	MIN	MAX
Α		20.35		0.801
В	14.70	15.20	0.579	0.598
С	4.70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
Е	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
Н	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L		16.20		0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157	REF
V	1.75 REF		0.0	)69

- STYLE 1:
  PIN 1. BASE
  2. COLLECTOR
  3. EMITTER

  - COLLECTOR

TO-247 CASE 340L-02 ISSUE F



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
  Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	20.32	21.08	0.800	8.30
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
Е	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
Н	1.50	2.49	0.059 0.098	
J	0.40	0.80	0.016	0.031
K	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242	BSC
W	2.87	3.12	0.113	0.123

# STYLE 3: PIN 1. BASE

- 2. COLLECTOR
  3. EMITTER
  4. COLLECTOR

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